

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	8	("5198683") or ("5670803") or ("5994735") or ("5627390").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/05 14:06
S2	2	"20040140502"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 11:51
S3	208	suzuki-yasumichi.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 14:06
S4	5	suzuki-yasumichi.in. and 'SRAM'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 14:12
S5	2	suzuki-yasumichi.in. and 'MISFET'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 14:08
S6	252	@ad<="20040114" and 'vertical' with 'MISFET'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 14:11
S7	864	(257/328).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 14:09
S8	826	@ad<="20040114" and (257/903).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 13:22
S9	238	@ad<="20040114" and (257/322).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 14:10
S10	785	@ad<="20040114" and (257/e21.661).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 14:10

EAST Search History

S11	634	@ad<="20040114" and (257/e27.098).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 14:10
S12	214	@ad<="20040114" and (438/212).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 11:43
S13	630	@ad<="20040114" and (438/268).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 14:11
S14	1036	@ad<="20040114" and (438/197).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 14:11
S15	55	@ad<="20040114" and (438/198).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 14:11
S16	194	@ad<="20040114" and 'vertical' and 'MISFET' and 'SRAM'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 10:07
S17	107	IWAI-HIDETOSHI.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 15:34
S18	18	IWAI-HIDETOSHI.in. and 'SRAM'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 14:12
S19	34	IWAI-HIDETOSHI.in. and 'mask'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 15:34
S20	156	@ad<="20040114" and 'vertical' and 'MISFET' and 'SRAM' and 'mask'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 14:06
S21	19	'Murata' and 'Renesas'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 09:09

EAST Search History

S22	144	'nakamura' and 'Renesas'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 09:11
S23	294	'suzuki' and 'Renesas'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 09:11
S24	36	'suzuki' and 'Renesas' and 'vertical'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 09:11
S25	43	'suzuki' and 'Renesas' and 'SRAM'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 09:11
S26	22	'nakamura' and 'Renesas' and 'SRAM'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 09:11
S27	88	@ad<="20040114" and 'vertical MISFET'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 11:25
S28	686	@ad<="20040114" and 'SRAM' and 'MISFET'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 11:16
S29	1	"5936280".PN.	USPAT; USOCR	OR	ON	2005/10/04 10:11
S30	264	@ad<="20040114" and 'SRAM' and 'MISFET' and 'dielectric'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 11:08
S31	2	("6483136").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/04 10:39
S32	1	"5472893".PN.	USPAT; USOCR	OR	ON	2005/10/04 10:41

EAST Search History

S34	7	@ad<="20040114" and 'vertical' with 'FET' and 'first dielectric' and 'second dielectric' and 'third dielectric'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 11:10
S35	171	@ad<="20040114" and 'vertical' with 'conductive' and 'first dielectric' and 'second dielectric' and 'third dielectric'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 11:10
S36	0	@ad<="20040114" and 'MISFET' and 'conductive side wall' and 'first dielectric' and 'second dielectric' and 'third dielectric'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 16:11
S37	2	@ad<="20040114" and 'MISFET' and 'conductive side wall' and 'dielectric'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 11:11
S39	6	@ad<="20040114" and 'MISFET' and 'conductive sidewall'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 11:17
S40	111	@ad<="20040114" and 'columnar' and 'conductive' with 'side wall'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 11:18
S41	273	@ad<="20040114" and 'columnar' and 'conductive' with ('side wall' or 'sidewall')	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 11:35
S42	2237	@ad<="20040114" and 'vertical' with 'FET'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 11:38
S43	18	@ad<="20040114" and 'columnar' and 'conductive' with ('side wall' or 'sidewall') and 'RAM'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 11:35
S44	627	@ad<="20040114" and 'vertical' with 'FET' and 'memory'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 11:38
S45	99	@ad<="20040114" and (438/222).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 11:43

EAST Search History

S46	83	@ad<="20040114" and (438/206).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 11:43
S47	0	'masaru hisamoto' and 'hitachi'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 13:23
S48	136	'hisamoto' and 'hitachi'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 13:23
S49	114	@ad<="20040114" and 'MISFET' and 'dielectric' same 'cvd' same 'temperature'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 14:07
S51	0	@ad<="20040114" and 'silicon nitride' same 'depostition' same 'cvd' same 'temperature'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 14:08
S53	448	@ad<="20040114" and 'silicon nitride' with 'deposition' same 'cvd' with 'temperature'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 14:09
S54	246	@ad<="20040114" and 'silicon nitride' with 'deposition' with 'cvd' with 'temperature'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 14:09
S55	165	'TEOS' same 'CVD' with 'tetraethoxysilane' same 'silicon nitride'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 14:52
S56	53	'TEOS' same 'CVD' with 'tetraethoxysilane' with 'silicon nitride'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 14:52
S57	53	'TEOS' with 'CVD' with 'tetraethoxysilane' with 'silicon nitride'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 15:12
S58	106	'silicon nitride' with 'silicon oxide' with 'Cvd' same 'tetraethoxysilane'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 15:00

EAST Search History

S59	441	@ad<="20040114" and 'TEOS' with 'silicon oxide' with 'CVD' with 'tetraethoxysilane'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 15:15
S60	184	@ad<="20040114" and 'TEOS' with 'silicon oxide' with 'CVD' with 'tetraethoxysilane' and 'ozone' and 'temperature'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 15:15
S61	27	@ad<="20040114" and 'TEOS' with 'silicon oxide' with 'CVD' with 'tetraethoxysilane' same 'ozone' same 'temperature'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 15:41
S62	4	@ad<="20040114" and 'TEOS' with 'silicon oxide' with 'CVD' with 'tetraethoxysilane' same 'ozone' same 'plasma' with 'density'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 15:47
S65	24	@ad<="20040114" and 'silicon oxide' with 'CVD' same 'plasma density'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 15:48
S66	23	@ad<="20040114" and 'silicon oxide' with 'CVD' same 'plasma density' and '10'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 15:49
S67	3	@ad<="20040114" and 'silicon oxide' with 'CVD' same 'plasma density' and "10.sup.11"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 15:51
S68	4	@ad<="20040114" and 'silicon oxide' same 'CVD' same 'plasma density' and "10.sup.11"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 15:51
S70	422	@ad<="20040114" and 'MISFET' and 'hitachi' and 'SRAM'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 16:16
S73	2	@ad<="20040114" and 'MISFET' and 'hitachi' and 'SRAM' and 'elliptical'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 16:16
S74	7	@ad<="20040114" and 'MISFET' and 'SRAM' and 'elliptical'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/04 16:17